

RD74LVC1G126

Bus Buffer with 3-state Output

REJ03D0732-0100 Rev.1.00 Apr 13, 2006

Description

The RD74LVC1G126 has bus buffer with 3–state output in a 5-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

• The basic gate function is lined up as renesas uni logic series.

• Supply voltage range: 1.65 to 5.5 V

• Operating temperature range: -40 to +85°C

• All inputs: V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)

• All outputs: V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)

• Output current: $\pm 4 \text{ mA } (@V_{CC} = 1.65 \text{ V})$

 $\pm 8 \text{ mA } (@V_{CC} = 2.3 \text{ V})$

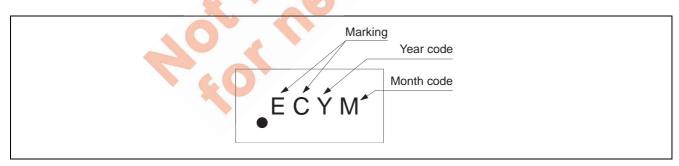
 $\pm 24 \text{ mA } (@V_{CC} = 3.0 \text{ V})$

 $\pm 32 \text{ mA } (@V_{CC} = 4.5 \text{ V})$

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC1G126WPE	WCSP-5 pin	SXBG0005LB-A	WP	E (3,000 pcs/reel)
		(TBS-5CV)		

Article Indication



Function Table

Inp		
OE	Α	Output Y
Н	Н	Н
Н	L	L
L	X	Z

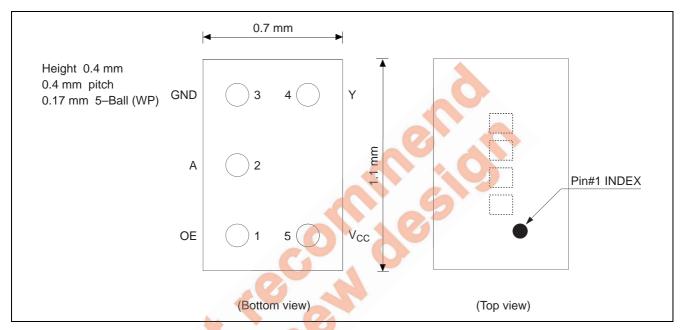
H: High level

L: Low level

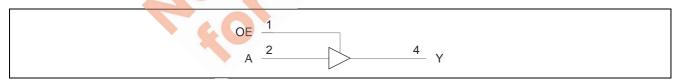
X: Immaterial

Z: High impedance

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	-0.5 to 6.5	V	
Input voltage range *1	VI	-0.5 to 6.5	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} +0.5	V	Output: H or L
		-0.5 to 6.5		V _{CC} : OFF or Output "Z"
Input clamp current	I _{IK}	-50	mA	V _I < 0
Output clamp current	I _{OK}	-50	mA	V _O < 0
Continuous output current	I _O	±50	mA	$V_O = 0$ to V_{CC}
Continuous current through	I _{CC} or I _{GND}	±100	mA	
V _{CC} or GND				
Package Thermal impedance	θ_{ja}	200	°C/W	WP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	1.65	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	
		0	5.5		Output : Z
Output current	l _{OL}		4	mA	V _{CC} = 1.65 V
			8		V _{CC} = 2.3 V
			16		$V_{CC} = 3.0 \text{ V}$
	40	-11	24		
			32		V _{CC} = 4.5 V
	ОН		-4		V _{CC} = 1.65 V
		_	-8		V _{CC} = 2.3 V
	4	_	-16		$V_{CC} = 3.0 \text{ V}$
		_	-24		
		_	-32		V _{CC} = 4.5 V
Input transition rise or fall rate	Δt / Δv	0	20	ns / V	$V_{CC} = 1.65 \text{ to } 1.95 \text{ V},$
	· ·				2.3 to 2.7 V
		0	10		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	5		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test condition
Input voltage	V_{IH}	1.65 to 1.95	V _{CC} ×0.65	_	_	V	
		2.3 to 2.7	1.7				
		3.0 to 3.6	2.0	1	1		
		4.5 to 5.5	V _{CC} ×0.7	1	1		
	V_{IL}	1.65 to 1.95		1	V _{CC} ×0.35		
		2.3 to 2.7			0.7		
		3.0 to 3.6	_	_	0.8		
		4.5 to 5.5	_	_	V _{CC} ×0.3		
Output voltage	V _{OH}	Min to Max	V _{CC} -0.1	_	_	V	$I_{OH} = -100 \ \mu A$
		1.65	1.2				$I_{OH} = -4 \text{ mA}$
		2.3	1.9				$I_{OH} = -8 \text{ mA}$
		3.0	2.4				$I_{OH} = -16 \text{ mA}$
			2.3	_	_		$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_		A	$I_{OH} = -32 \text{ mA}$
	V_{OL}	Min to Max	_	_	0.1		I _{OL} = 100 μA
		1.65	_	_	0.45		$I_{OL} = 4 \text{ mA}$
		2.3	_		0.3		$I_{OL} = 8 \text{ mA}$
		3.0	_		0.4	A	$I_{OL} = 16 \text{ mA}$
			_	-10	0.55	10	l _{oL} = 24 mA
		4.5	_		0.55	X	l _{OL} = 32 mA
Input current	I _{IN}	0 to 5.5			±5	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state Output current	loz	3.6	-	_	10	μΑ	$V_0 = 5.5 \text{ V or GND}$
Quiescent supply current	Icc	1.65 to 5.5			10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
	Δlcc	3 to 5.5	9	1/2	500		One input at V _{CC} –0.6 V, Other input at V _{CC} or GND
Output leakage current	l _{OFF}	0	7	9 —	±10	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	CIN	3.3		3.5	_	pF	V _{IN} = V _{CC} or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=1.8{\pm}0.15~V$

		Ta = -40 to 85°C				FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	2.6	8.0	ns	$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	А	Υ
	t _{PHL}						
Output enable time	t_{ZH}	2.8	9.4	ns		OE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	1.6	9.8	ns		OE	Υ
	t_LZ						

 $V_{CC}=2.5{\pm}0.2~V$

		Ta = -40 to 85°C				FROM	ТО
ltem	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.1	5.5	ns	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	Α	Υ
	t _{PHL}						
Output enable time	t_{ZH}	1.3	6.6	ns		OE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	1.0	5.5	ns		OE	Υ
	t_{LZ}						

	·				0,70	V_{CC}	= 3.3±0.3 V
		Ta = -40) to 85°C			FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.0	4.5	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	Α	Υ
	t _{PHL}				16		
Output enable time	t _{zH}	1.2	5.3	ns		OE	Υ
	t_{ZL}						
Output disable time	t _{HZ}	1.0	5.5	ns		OE	Υ
	t _{LZ}						

 $V_{CC} = 5.0 \pm 0.5 \text{ V}$

						CC	
	9	Ta = −40 to 85°C				FROM	ТО
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.0	4.0	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	Α	Υ
	t _{PHL}						
Output enable time	t _{ZH}	1.0	5.0	ns		OE	Υ
	tzL						
Output disable time	t _{HZ}	1.0	4.2	ns		OE	Υ
	t_LZ						

Operating Characteristics

				Ta = 25°C			
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation	C_{PD}	1.8	_	19	_	pF	f = 10 MHz
capacitance		2.5	_	19	_		
		3.3	_	20	_		
		5.0		22	_		

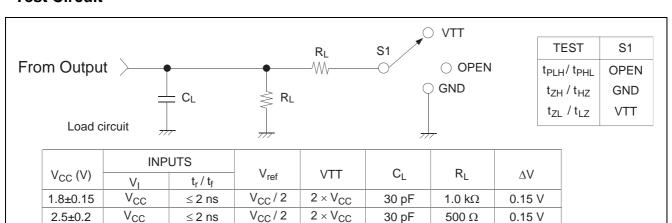
Test Circuit

 3.3 ± 0.3

Output Y

(Waveform - B)

 V_{CC}



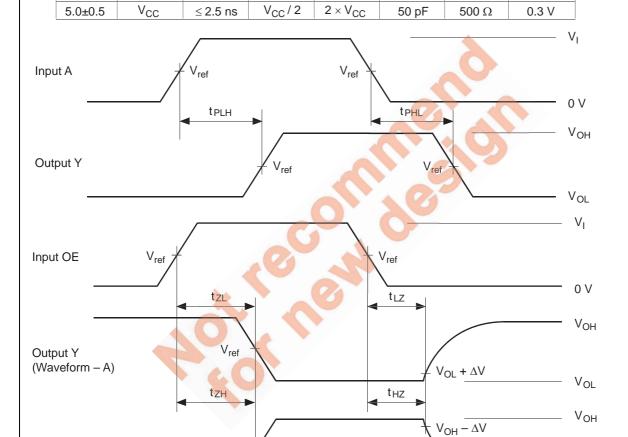
6 V

50 pF

 500Ω

0.3 V

 V_{OL}



1.5 V

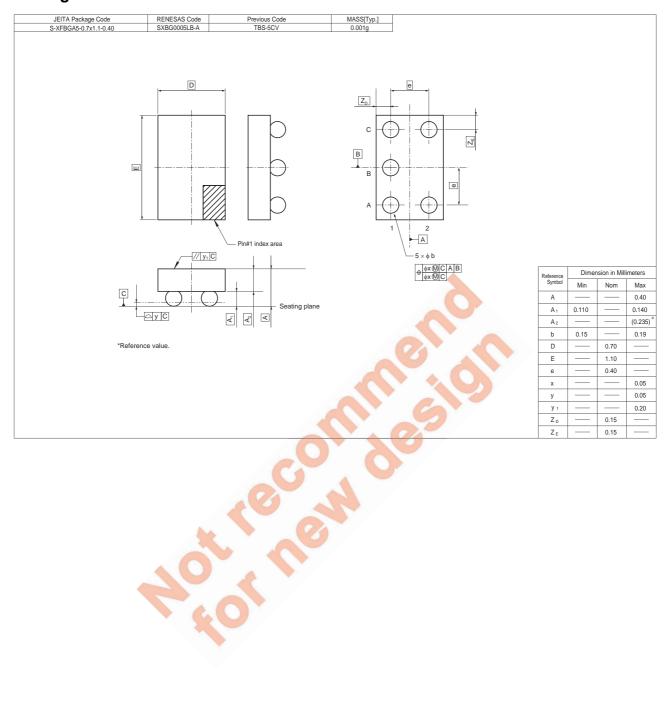
 \leq 2.5 ns

Notes: 1. C_L includes probe and jig capacitance.

 V_{ref}

- 2. Waveform—A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform–B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, Zo = 50 $\Omega.$
- 5. The output are measured one at a time with one transition per measurement.

Package Dimensions



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